

UNIVERSITI PUTRA MALAYSIA

STRUCTURAL AND MAGNETOTRANSPORT PROPERTIES OF BULK RARE EARTH BARIUM MANGANITE AND (La, Pr)-Ba-Mn-O SINGLE-AND BI-LAYER THIN FILMS

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By

WONG JEN KUEN

Thesis Submitted to the School of Graduate Studies, Universiti Putra Malaysia, in Fulfillment of the Requirement for the Degree of Master of Science

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To My Family Members and Friends......

Abstract of thesis presented to the Senate of Universiti Putra Malaysia in fulfillment of the requirement for the degree of Master of Science.

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September 2011

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Magnetoresistance based sensor had been long used in magnetic field sensing application. Higher sensitivity and smaller in size is essential to keep up with the increasing of magnetic storage density. In this work, magnetotransport and magnetic properties of manganites are studied in both bulk and thin films. The influence of different rare earth cation in Ln site of bulk $Ln_{0.67}Ba_{0.33}MnO_3$ (Ln= La, Ce, Pr, Nd, Sm, Gd, Dy and Er) compound synthesized via conventional solid state reaction route was studied. All substituted compound are in single phase except Ce, Dy and Er which are in oxide mixture due to differences in enthalpy of fusion. The crystal system undergoes transformation from orthorhombic to tetragonal when larger (La) cation was substituted by smaller (Gd) cation into Ln site. Substitution of smaller cation at Ln site increases the resistivity and shifts the phase transition temperature,T_P and Curie temperature,T_C to lower temperature. At room temperature, the ferromagnetic $La_{0.67}Ba_{0.33}MnO_3$ (LBMO) undergoes magnetic dilution (glassy magnetic state) and became paramagnetic due to



spin pinning effect when substituted by smaller rare earth cation. The highest room temperature negative %MR was given by Gd_{0.67}Ba_{0.33}MnO₃ (GBMO) with -34.09% in 10kG. Substitution of smaller rare earth element into Ln site could enhance the %MR but results in the formation of complicated glassy magnetic state. The work then extended by fabrication of single and bi-layer (LBMO and/or PBMO) thin films through pulsed laser deposition technique on different type of substrate. Upon converted into thin film, the crystal systems remain orthorhombic. The unit cell of both LBMO and PBMO single layer thin films experience positive misfit due to lattice strain induced from lattice misfit between film and substrate. For bi-layer thin films, the lattice misfit is sequence dependent where negative misfit in PB/LB coupling and positive misfit in LB/PB coupling. The resistivity is higher for single layer thin film having more and larger nanocracks when deposited on substrate with smaller coefficient of thermal expansion. The resistivity of bi-layer thin films grown on amorphous substrate is lower than single layer thin films and is contrary on MgO substrate. T_P shifted to lower temperature (<80K) in thin film form. The room temperature magnetic properties of single layer thin films were substrate dependent where PBMO growth on amorphous substrates was more ferromagnetic and vice versa for LBMO. However, room temperature magnetic properties between LB/PB and PB/LB bi-layer films are different. The magnetizations are relatively smaller as compared to single layer thin films (LBMO or PBMO) due to magnetic pinning effect. Their magnetization values were substrate dependent as well as stacking sequence on amorphous substrate but not for single crystal substrate. Typical polycrystalline manganites behavior was observed in all thin film samples where %MR further increase at lower temperature. This shows the extrinsic CMR behavior originated from grain boundary is stronger in thin films compared to bulk. Indeed, conversion from

iv

bulk to thin film can enhance %MR value. Single layer LBMO thin films growth on amorphous substrate shows low field magnetoresistance (LFMR) effect and further enhancement in bi-layer films but not on single crystal MgO substrate. Improvement of %MR value of -28.8% from bulk LBMO to -35.90% (LBMO-FS), -34.60% (LBMO-CG) and -31.40% (LBMO-M) were observed at temperature of 80K in 10kG. The highest negative %MR and LFMR value obtained in this work was PBMO-M (-50.00%) and PB/LB-FS (-12.40%) at temperature of 80K in 10kG respectively whereas the highest room temperature negative %MR in 10kG was given by bulk GBMO (-34.09%).

Abstrak tesis yang dikemukakan kepada Senat Universiti Putra Malaysia sebagai memenuhi keperluan untuk ijazah Master Sains.

SIFAT-SIFAT STRUKTUR DAN PENGANGKUTAN MAGNETO NADIR BUMI BARIUM MANGANAT DALAM BENTUK PUKAL DAN FILEM-FILEM NIPIS (La,Pr)-Ba-Mn-O BERLAPIS TUNGGAL DAN DWI LAPISAN

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Sensor magnetorintangan telah lama digunakan dalam aplikasi pengesanan medan magnet. Sensitiviti yang lebih tinggi dan saiz yang lebih kecil adalah sangat penting dengan pertambahan ketumpatan simpanan magnet. Dalam penyelidikan ini, pengangkutan magneto dan sifat-sifat kemagnetan manganat dikaji dalam bentuk pukal dan filem nipis. Pengaruh daripada kation nadir bumi yang berbeza di tapak Ln dalam sebatian $Ln_{0.67}Ba_{0.33}MnO_3$ (Ln= La, Ce, Pr, Nd, Sm, Gd, Dy dan Er) disintesis dengan kaedah tindak balas keadaan pepejal yang konvensional telah dikaji. Semua sebatian yang disubstitusi menunjukkan fasa tunggal kecuali Ce, Dy dan Er yang wujud dalam campuran oksida disebabkan oleh perbezaan dalam enthalpi lakuran. Sistem hablur mengalami transformasi daripada ortorombus kepada tetragon apabila kation (La) yang lebih besar digantikan dengan kation (Gd) yang lebih kecil ke dalam tapak Ln. Penggantian kation yang lebih kecil meningkatkan keringtangan dan menggeserkan suhu peralihan fasa, T_P dan suhu Curie, T_C ke suhu yang lebih rendah. Pada suhu bilik,

feromagnet La_{0.67}Ba_{0.33}MnO₃ (LBMO) mengalami pencairan magnet (keadaan magnetik yang rumit) dan menjadi paramagnet akibat kesan sematan spin yang disebabkan oleh kation nadir bumi yang lebih kecil. %MR negatif yang tertinggi pada suhu bilik diberi oleh GBMO (-34.09%) dalam 10kG. Penggantian kation nadir bumi yang lebih kecil ke dalam tapak Ln boleh meningkatkan %MR tetapi mengakibatkan pembentukan keadaan magnet yang merumitkan. Kajian ini kemudian dilanjutkan dengan menyediakan filem nipis (LBMO dan/atau PBMO) berlapis tunggal dan dwi lapisan dengan teknik mendapan dedenyut laser (PLD) pada jenis substrat yang berbeza. Setelah ditukar menjadi filem nipis, struktur hablur masih kekal ortorombus. Sel unit daripada keduadua jenis filem nipis LBMO dan PBMO berlapis tunggal mengalami tidak seragam positif disebabkan regangan kekisi yang terhasil daripada tidak seragaman kekisi antara filem dan substrat. Untuk filem nipis dwi lapisan, tidak seragaman kekisi adalah bergantung kepada urutannya dimana tidak seragam negatif dalam gandingan PB/LB dan tidak seragam positif dalam gandingan LB/PB. Keringtangan adalah lebih besar untuk filem nipis berlapis tunggal dengan retakan bersaiz nano yang lebih banyak dan lebih besar apabila dimendap ke atas substrat dengan pekali pengembangan terma yang lebih kecil. Sebagai perbandingan, keringtangan filem-filem nipis dwi lapisan tumbuh di atas substrat amorfus adalah lebih rendah daripada filem-filem nipis berlapis tunggal dan adalah bersongsangan pada substrat MgO. T_P beranjak ke suhu yang lebih rendah (<80K) apabila bertukar ke bentuk filem nipis. Sifat-sifat magnet suhu bilik filem-filem yang berlapis tunggal adalah bergantung kepada substrat yang digunakan dengan pertumbuhan PBMO pada substrat amorfus adalah lebih feromagnet dan adalah bersongsangan untuk LBMO. Walau bagaimanapun, sifat-sifat magnet pada suhu bilik antara filem LB/PB dan PB/LB dwi lapisan adalah berlainan antara satu sama lain dan lebih kecil berbanding dengan filem-filem nipis berlapis tunggal (LBMO atau PBMO) akibat kesan sematan spin. Nilai-nilai kemagnetan adalah bergantung kepada substrat yang digunakan dan susunan urutan pada substrat amorfus tetapi bukan untuk substrat hablur tunggal. Peranan yang biasa untuk polihabluran manganat telah diperhatikan dalam semua sampel filem nipis dimana %MR adalah bertambah berterusan pada suhu yang lebih rendah. Oleh demikian, peranan CMR ekstrinsik yang berasal dari sempadan butiran adalah lebih kuat di dalam filem-filem nipis berbanding dalam bentuk pukal. Justeru itu, penukaran daripada bentuk pukal ke filem nipis boleh meningkatkan nilai %MR. Filem nipis LBMO berlapis tunggal yang ditumbuhkan pada substrat amorfus menunjukkan kesan magnetorintangan medan rendah (LFMR) dan meningkat dalam filem-filem nipis dwi lapisan tetapi bukan pada substrat hablur tunggal MgO. Manakala, peningkatan nilai %MR -28.8% daripada bentuk pukal LBMO kepada -35.90% (LBMO-FS), -34.60% (LBMO-CG) dan -31.40% (LBMO-M) telah diperhatikan pada suhu 80K dalam 10kG. Nilai %MR dan LFMR negatif tertinggi masing-masing diperolehi dalam kajian ini ialah PBMO-M (-50.00%) dan PB/LB-FS (-12.40%) pada suhu 80K dalam 10kG manakala %MR negatif yang tertinggi pada suhu bilik dalam 10kG diberi oleh GBMO (-34.09%) dalam bentuk pukal.

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DECLARATION

I declare that the thesis is my original work except for quotations and citations which have been duly acknowledged. I also declare that it has not been previously, and is not concurrently, submitted for any other degree at Universiti Putra Malaysia or at any other institution.



TABLE OF CONTENTS

DEDICATION	ii
ABSTRACT	iii
ABSTRAK	vi
ACKNOWLEDGEMENTS	ix
APPROVAL	xi
DECLARATION	xiii
LIST OF TABLES	xviii
LIST OF FIGURES	xix
LIST OF ABBREVIATIONS/NOTATIONS/GLOSSARY OF TERMS	xxvii

CHAPTER

1	INTE	INTRODUCTION					
	1.1	General Background	1				
	1.2	Application of Colossal Magnetoresistance					
	1.3	Problem Statement	2				
	1.4	Objective of the Thesis	3				
	1.5	Thesis Organization	4				
2	LITE	CRATURE REVIEW					
	2.1	2.1 Historical Background of Perovskite Manganite					
	2.2	Lanthanum Based Manganese Oxide	7				
	2.3	Single and Polycrystalline Crystal Manganite	8				
	2.4	Polycrystalline and Epitaxial Films	11				
	2.5	Intrinsic and Extrinsic CMR Characteristic in	13				
		Polycrystalline Manganite					
	2.6	Electrical Behaviour of Manganites	14				
	2.7	Critical Features of Colossal Magnetoresistance	15				
		Manganites					
		2.7.1 Structural Considerations	15				
		2.7.2 Relationship between T_P , T_C and CMR Effect	16				
	2.8	Adjusting Some Parameters for Desirable CMR Effect	18				
		2.8.1 Composition Modification via Different Sizes of Rare Earth Cation	18				
		2.8.2 Influence of Substrates in Thin Film Manganites	20				
		2.8.3 Bi-layer Thin Film Manganites	25				

THEC)RY					
3.1	Perov	skite Stru	cture	29		
3.2	La Based Doped Manganites ($La_{1-x}AE_xMnO_3$)					
3.3	Defini	Definition of Magnetoresistance				
3.4	Type of	be of Magnetoresistance				
3.5	Magne	netoresistance in CMR				
3.6	Doubl	e Exchan	ge Mechanism	34		
3.7	Crysta	l Field E	ffect and Jahn Teller Distortions	37		
3.8	Magne	etic Mate	rial	39		
	3.8.1	Transiti	on from Paramagnetism to	42		
		Ferroma	gnetism			
3.9	Solid	State Rea	ction	42		
3.10	Funda	mental of	Thin Film Growth	43		
	3.10.1	Growth	mode, Pulsed Laser Deposition (PL	D) 43		
	3.10.2	Film Nu	cleation and Growth	46		
		3.10.2.1	Initial Nucleation and Growth	46		
		3.10.2.2	Growth Modes	47		
	3.10.3	Epitaxia	l Growth	49		
	3.10.4	Lattice S	Strain Effect	51		
MATI	ERIAL	S AND N	IETHODS			
4.1 Materials Selection						
4. <mark>2</mark>	Sample Preparation					
	4.2.1	Solid S	tate Reaction (SSR) for Bulk Cl	MR 55		
		Samples				
		4.2.1.1	Chemical Equation balance	ing, 55		
			Powders and Wet Milling	ing		
		4212	Powder Calcination	56		
		4213	Grinding Sieving and Pelletizing	50		
		4.2.1.3	Sintering	58		
	122	Pulsed 1	aser Deposition (PLD) for Thin F	50 jilm 59		
	т.2.2	CMR Sa	amples	1111 J)		
		4.2.2.1	Single and Bi-layer Thin F	ilm 61		
			Deposition	-		
	4.2.3	Anneali	ng	61		
4.3	Sample Characterization					
	4.3.1	Structur	e Characterization	62		
		4.3.1.1	X-ray Diffraction	62		
			4.3.1.1.1 Powder Scan	63		
			4.3.1.1.2 Thin Film Scan	63		

3

		4.3.1.2 Rietveld Refinement			
		4.3.1.3 Scherrer Equation			
	4.3.2	Surface Morphology and Microstructure Characterization			
		4.3.2.1 Scanning Electron Microscope	66		
		4.3.2.2 Field Emission Scanning Electron Microscope	66		
	4.3.3	Element Composition Characterization	67		
	4.3.4	Magnetic Characterization	68		
		4.3.4.1 Vibrating Sample Magnetometer	68		
		4.3.4.2 Superconducting Quantum	69		
		Interference Device Magnetometer (SQUID)			
	4.3.5	Electrical Measurement	69		
		4.3.5.1 Resistivity	70		
		4.3.5.2 Magnetoresistance	72		
	4.3.6	Film Thickness Characterization	72		
	4.3.7	Accuracy of Measurements	73		
RESU	JLTS A	ND DISCUSSIONS			
5.1	Bulk	Colossal Magnetoresistance Compound	74		
	5.1.1	Structure and Phase Characterization	75		
	5.1.2	Microstructure Analysis			
	5.1.3	Magnetization and Curie temperature, T_C			
	5.1.4	Resistivity and Phase Transition Temperature, T_P	85		
	5.1.5	Colossal Magnetoresistance Effect	86		
	5.1.6	Summary	90		
5.2	Single	e Layer Thin Film	91		
	5.2.1	Single Layer Thin Film of La _{0.67} Ba _{0.33} MnO ₃	91		
		5.2.1.1 Structure and Phase Characterization	92		
		5.2.1.2 Microstructure Analysis	96		
		5.2.1.3 Hysteresis Loops	98		
		5.2.1.4 Resistivity and Phase Transition Temperature, T_P	99		
		5.2.1.5 Colossal Magnetoresistance Effect	101		
		5.2.1.6 Summary	104		
	5.2.2	Single Layer Thin Film of Pr _{0.67} Ba _{0.33} MnO ₃	106		
		5.2.2.1 Structure and Phase Characterization	106		
		5.2.2.2 Microstructure Analysis	110		
		5.2.2.3 Hysteresis Loops	112		

			5.2.2.4	Resistivity and Phase Transition	114
			5225	Colossal Magnetoresistance Effect	115
			5.2.2.6	Summary	119
	5.3	Bi-laye	er Thin Fil	lm	120
		5.3.1	Structure	and Phase Characterization	121
		5.3.2	Microstru	ucture Analysis	129
		5.3.3	Hysteres	is Loops	133
		5.3.4	Resistivit T _P	ty and Phase Transition Temperature,	136
		5.3.5	Colossal	Magnetoresistance Effect	139
		5.3.6	Summary	/	145
6	CON	CLUSI	ON AND S	SUGGESTIONS	
	6.1	Conclu	ision		147
	6.2	Recom	mendation	n of Future Work	150
REFERENC	ES/BIB	LIOGH	RAPHY		151
APPENDICH	ES				163
BIODATA OF THE AUTHOR					204
LIST OF PUBLICATIONS 2				205	

C